NSN 5962-01-372-9181

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View Online at https://aerobasegroup.com/nsn/5962-01-372-9181

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Body Length:
Between 1.040 inches and 1.060 inches
Body Width:
Between 0.290 inches and 0.310 inches
Body Height:
Between 0.180 inches and 0.200 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Eolorops
Features Provided:
Bipolar and electrostatic sensitive and monolithic and programmed and burn in, mil-std-883, class b and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Input Circuit Pattern:
16 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, programmed
Voltage Rating And Type Per Characteristic:
4.5 volts total supply and 5.5 volts total supply
Memory Device Type:
Pal

Special Features:

Esd; altered item using 67268, 5962-8515520rx; checksum 2b2e; file name 1060 u15.Jed

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

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Spe	cific	ation	Data
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67268-5962-85155 government standard

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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